

December 2006

H11L1M, H11L2M, H11L3M 6-Pin DIP Optocoupler

Features

- High data rate, 1MHz typical (NRZ)
- Free from latch up and oscilliation throughout voltage and temperature ranges.
- Microprocessor compatible drive
- Logic compatible output sinks 16mA at 0.4V maximum
- Guaranteed on/off threshold hysteresis
- Wide supply voltage capability, compatible with all popular logic systems
- Underwriters Laboratory (UL) recognized file #E90700, Volume 2
- VDE recognized File#102497 Add option V (e.g., H11LIVM)

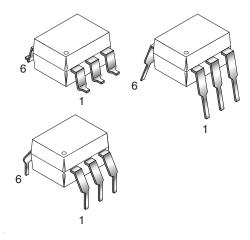
Applications

- Logic to logic isolator
- Programmable current level sensor
- Line receiver—eliminate noise and transient problems
- A.C. to TTL conversion—square wave shaping
- Digital programming of power supplies
- Interfaces computers with peripherals

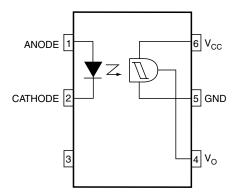
Description

The H11LXM series has a high speed integrated circuit detector optically coupled to a gallium-arsenide infrared emitting diode. The output incorporates a Schmitt trigger, which provides hysteresis for noise immunity and pulse shaping. The detector circuit is optimized for simplicity of operation and utilizes an open collector output for maximum application flexibility.

Packages



Schematic



Truth Table

Input	Output
Н	L
L	Н

Absolute Maximum Ratings ($T_A = 25^{\circ}C$ Unless otherwise specified.)

Symbol	Parameters	Value	Units			
TOTAL DEVICE	TOTAL DEVICE					
T _{STG}	Storage Temperature	-55 to +150	°C			
T _{OPR}	Operating Temperature	-40 to +85	°C			
T _{SOL}	Lead Solder Temperature	260 for 10 sec	°C			
P _D	Total Device Power Dissipation @ 25°C	250	mW			
	Derate Above 25°C	2.94	mW/°C			
EMITTER						
I _F	Continuous Forward Current	60	mA			
V _R	Reverse Voltage	6	V			
I _F (pk)	Forward Current - Peak (1µs pulse, 300pps)	3.0	А			
P_{D}	LED Power Dissipation 25°C Ambient	120	mW			
	Derate Linearly From 25°C	1.41	mW/°C			
DETECTOR						
P _D	Detector Power Dissipation @ 25°C	150	mW			
	Derate Linearly from 25°C	2.0	mW/°C			
V _O	V ₄₅ Allowed Range	0 to 16	V			
V _{CC}	V ₆₅ Allowed Range	3 to 16	V			
I _O	I ₄ Output Current	50	mA			

Electrical Characteristics (T_A = 25°C Unless otherwise specified.)

Individual Component Characteristics

Symbol	Parameters	Test Conditions	Device	Min.	Тур.	Max.	Units
EMITTER	•						
V _F	Input Forward Voltage	I _F = 10mA	All		1.2	1.5	V
		I _F = 0.3mA		0.75	1.0		
I _R	Reverse Current	V _R = 3V	All			10	μA
CJ	Capacitance	V = 0, f = 1.0MHz	All			100	pF
DETECTOR							
V _{CC}	Operating Voltage Range		All	3		15	V
I _{CC(off)}	Supply Current	$I_F = 0, V_{CC} = 5V$	All		1.6	5.0	mA
I _{OH}	Output Current, High	$I_F = 0, V_{CC} = V_O = 15V$	All			100	μΑ

Transfer Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Units
DC CHARA	CTERISTICS						
I _{CC(on)}	Supply Current	I _F = 10mA, V _{CC} = 5V	All		1.6	5.0	mA
V _{OL}	Output Voltage, low	R_L = 270 Ω , V_{CC} = 5V, I_F = $I_{F(on)}$ max.	All		0.2	0.4	V
I _{F(on)}	Turn-On Threshold Current ⁽¹⁾	$R_L = 270\Omega, V_{CC} = 5V$	H11L1M			1.6	mA
			H11L2M			10.0	
			H11L3M			5.0	
I _{F(off)}	Turn-Off Threshold Current	$R_L = 270\Omega$, $V_{CC} = 5V$	All	0.3	1.0		mA
I _{F(off)} /I _{F(on)}	Hysteresis Ratio	$R_L = 270\Omega$, $V_{CC} = 5V$	All	0.50	0.75	0.90	
AC CHARA	CTERISTICS, Switching Speed	d				,	
t _{on}	Turn-On time	$R_L = 270\Omega, V_{CC} = 5V,$ $I_F = I_{F(on)}, T_A = 25^{\circ}C$	All		1.0	4	μs
t _f	Fall Time	$R_L = 270\Omega, V_{CC} = 5V,$ $I_F = I_{F(on)}, T_A = 25^{\circ}C$	All		0.1		μs
t _{off}	Turn-Off Time	$R_L = 270\Omega, V_{CC} = 5V,$ $I_F = I_{F(on)}, T_A = 25^{\circ}C$	All		1.2	4	μs
t _r	Rise time	$R_L = 270\Omega, V_{CC} = 5V,$ $I_F = I_{F(on)}, T_A = 25^{\circ}C$	All		0.1		μs
	Data Rate		All		1.0		MHz

Isolation Characteristics

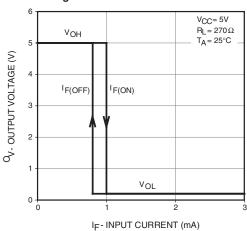
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
V _{ISO}	Input-Output Isolation Voltage	t =1 sec.	7500			V _{PEAK}
C _{ISO}	Isolation Capacitance	$V_{I-O} = 0V$, $f = 1MHz$		0.4	0.6	pF
R _{ISO}	Isolation Resistance	V _{I-O} = ±500 VDC	10 ¹¹			Ω

Note:

Maximum I_{F(ON)} is the maximum current required to trigger the output. For example, a 1.6mA maximum trigger current would require the LED to be driven at a current greater than 1.6mA to guarantee the device will turn on. A 10% guard band is recommended to account for degradation of the LED over its lifetime. The maximum allowable LED drive current is 60mA.

Typical Performance Curves

Figure 1. Transfer Characteristics



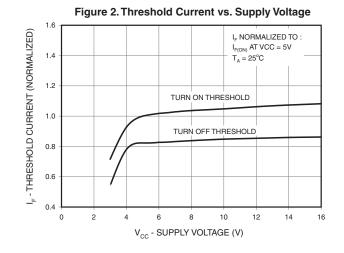


Figure 3. Threshold Current vs. Supply Temperature

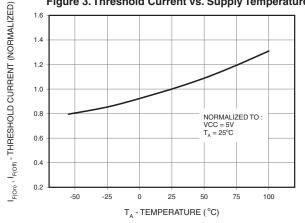


Figure 4. Output Voltage, Low vs. Load Current

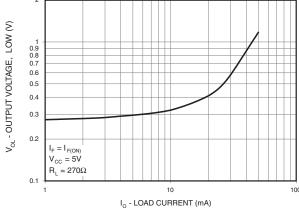


Figure 5. Supply Current vs. Supply Voltage

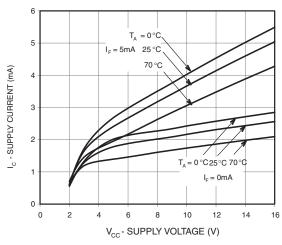
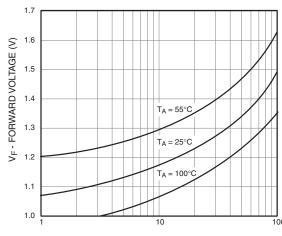


Figure 6. LED Forward Voltage vs. Forward Current



I_F - LED FORWARD CURRENT (mA)

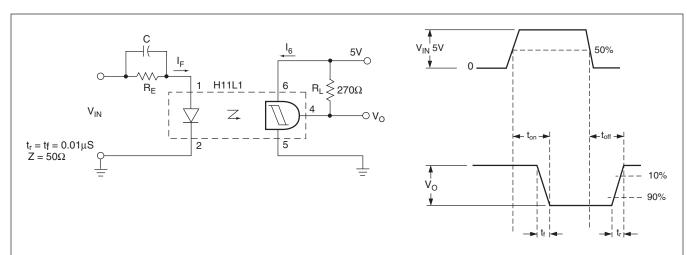
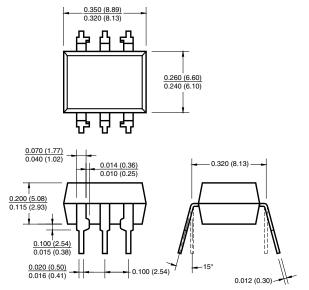


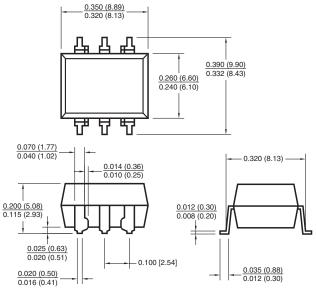
Figure 7. Switching Test Circuit and Waveforms

Package Dimensions

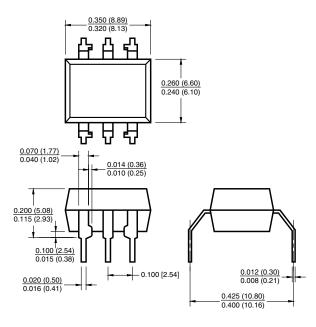
Through Hole



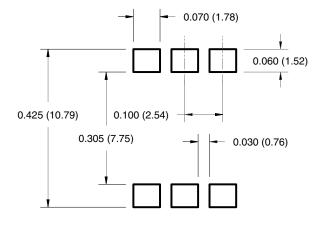
Surface Mount



0.4" Lead Spacing



Recommend Pad Layout for Surface Mount Leadform



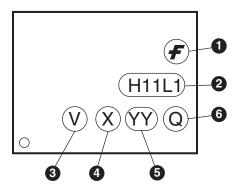
Note:

All dimensions are in inches (millimeters).

Ordering Information

Option/Order Entry Identifier	Description
S	Surface Mount Lead Bend
SR2	Surface Mount; Tape and reel
Т	0.4" Lead Spacing
V	VDE 0884
TV	VDE 0884, 0.4" Lead Spacing
SV	VDE 0884, Surface Mount
SR2V	VDE 0884, Surface Mount, Tape & Reel

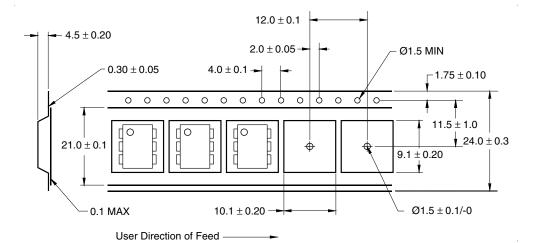
Marking Information



Definitions			
1	Fairchild logo		
2	Device number		
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)		
4	One digit year code, e.g., '3'		
5	Two digit work week ranging from '01' to '53'		
6	Assembly package code		

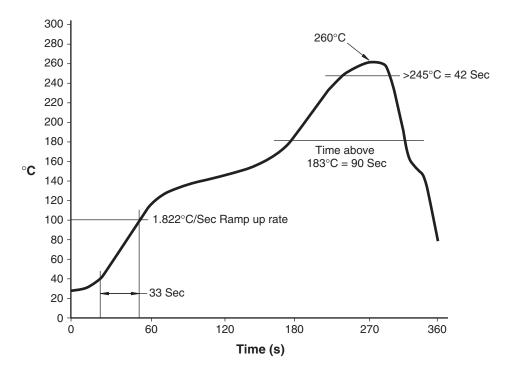
^{*}Note – Parts that do not have the 'V' option (see definition 3 above) that are marked with date code '325' or earlier are marked in portrait format.

Tape Dimensions



Note: All dimensions are in millimeters.

Reflow Profile





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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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